## 30V 170A N-Channel Enhancement Mode Power MOSFET

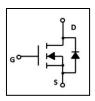
#### **Features**

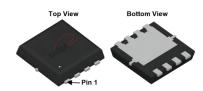
- RDSON $\leq$ 1.7m $\Omega$  @Vgs=10V
- Advanced SGT process
- Excellent RDS(ON) and Low Gate Charge
- · Lead free product is acquired

### **Application**

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

#### **SYMBOL**







PDFN5\*6

#### **ASSEMBLY MESSAGE**

Product Name	Package	Packaging		
BXS017N03C	PDFN5*6	Reel		

#### **ABSOLUTE MAXIMUM RATINGS** (Tc=25°C unless otherwise noted)

Parameter		Symbol	Rating PDFN5*6	Unit
Drain-Source Voltage		V <sub>DSS</sub>	30	V
Drain Current	Continuous (T <sub>C</sub> = 25°C)		85	А
(Package limit)	Continuous (T <sub>C</sub> = 100°C)	l <sub>D</sub>	58	Α
Drain Current	Continuous (T <sub>C</sub> = 25°C)		170	А
(Silicon limit)	Continuous (T <sub>C</sub> = 100°C)	l <sub>D</sub>	141	А
Drain Current	in Current Pulsed (Note1)		340	А
Single Pulsed Avalanche Energy		EAS	240	mJ
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Power Dissipation T <sub>C</sub> =25°C		P <sub>D</sub>	100	W
Maximum Junction Temperature		TJ	150	°C
Storage Temperature Range		Tstg	-55 to 150	°C

Note: 1. Repetitive Rating: Pulse width limited by maximum junction temperature

#### THERMAL CHARACTERISTICS

Parameter	Symbol	Max.	Unit	
Farameter	Symbol	PDFN5*6	Uill	
Thermal Resistance, Junction to Case	Rejc	1.25	°C / W	

# **ELECTRICAL CHARACTERISTICS** (T<sub>J</sub>=25°C,unless otherwise Noted)

Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit
OFF CHARACTERISTICS			•			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	VGS=0V, ID=250µA	30			V
Zero Gate Voltage Drain Current	IDSS	VDS=30V, VGS=0V			1	uA
Gate-Body Leakage Current, Forward	Igss	VGS=20V			100	nA
Gate-Body Leakage Current, Reverse		VGS=-20V			-100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	VDS=VGS, ID=250μA	1.2	1.6	2.5	V
D : 0	D	VGS=10V, ID=50A		1.3	1.7	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	VGS=4.5V, ID=30A		1.8	2.5	mΩ
DYNAMIC PARAMETERS						
Input Capacitance	Ciss	VDS=15V, VGS=0V,		3061		pF
Output Capacitance	Coss		1300		pF	
Reverse Transfer Capacitance	Crss	f=1.0MHz		30		pF
SWITCHING PARAMETERS						
Turn-ON Delay Time	t <sub>D(ON)</sub>			11		ns
Turn-ON Rise Time	t <sub>R</sub>	VDD=15V, ID=15A, VGS		39		ns
Turn-OFF Delay Time	t <sub>D(OFF)</sub>	= 10V, RG=3Ω		33		ns
Turn-OFF Fall-Time	t <sub>F</sub>			9		ns
Total Gate Charge(Note2)	$Q_{G}$	1/00 451/ 1/00 451/		20		nC
Gate Source Charge	Q <sub>GS</sub>	VDS =15V, VGS =4.5V, ID=15A		8		nC
Gate Drain Charge	Q <sub>GD</sub>			7		nC
SOURCE- DRAIN DIODE RATINGS	AND CHAR	ACTERISTICS				
Drain-Source Diode Forward Voltage	V <sub>SD</sub>	Is=30A, VGS=0V			1.4	V
Diode Continuous Forward Current	Is				85	Α
Maximum Pulsed Drain to Source Diode Forward Current	Іѕм				340	А

Note: 2. Essentially independent of operating temperature

7.5



#### TYPICAL CHARACTERISTICS

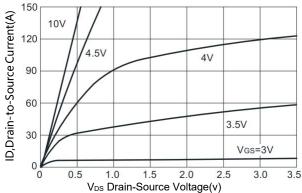


Figure 1. Typical Output Characteristics

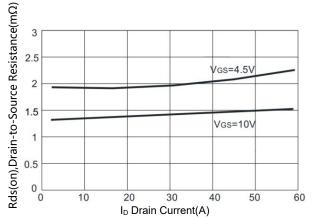
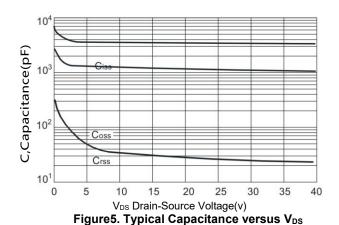


Figure 3. On-Resistance versus Drain Current



ID, Drain Current(A) 120 125℃ 90

150

30

0

3.0 4.5 6.1 V<sub>GS</sub> Gate-Source Voltage(v) Figure 2. Typical Transfer Characteristics

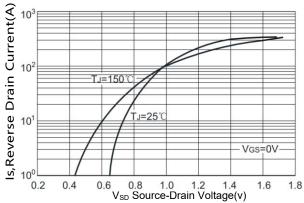


Figure 4. Diode forward voltage versus Current

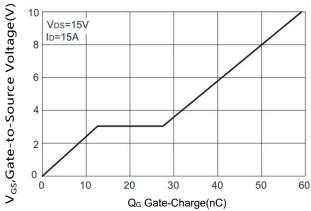


Figure 6. Typical Gate Charge versus V<sub>GS</sub>

# **TYPICAL CHARACTERISTICS(Cont.)**

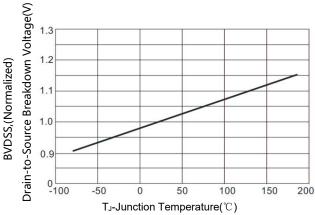


Figure 7. BV<sub>DSS</sub> Variation with Temperature

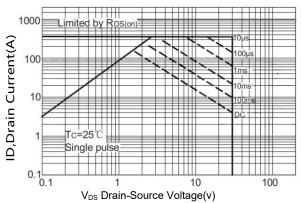


Figure 9. Maximum Safe Operating Area

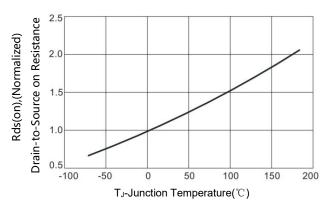


Figure 8. On-Resistance Variation with Temperature

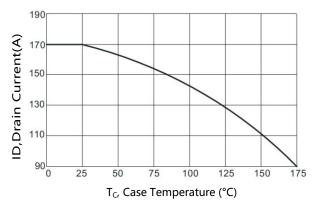
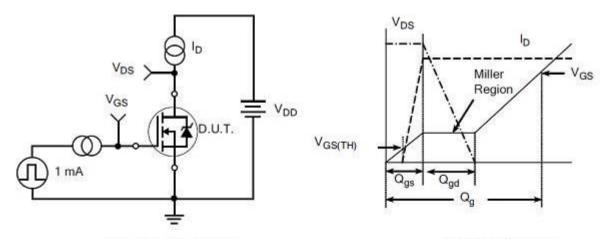


Figure 10. Maximum Continuous Drain Current versus Case Temperature

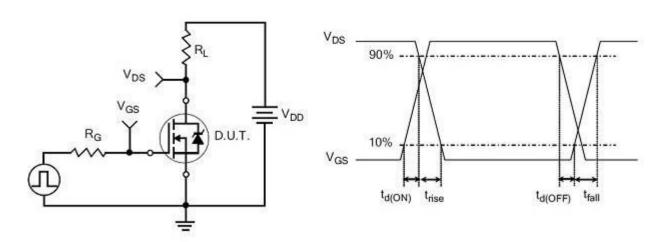


# **TEST CIRCUITS AND WAVEFORMS**



Gate Charge Test Circuit

Gate Charge Waveform

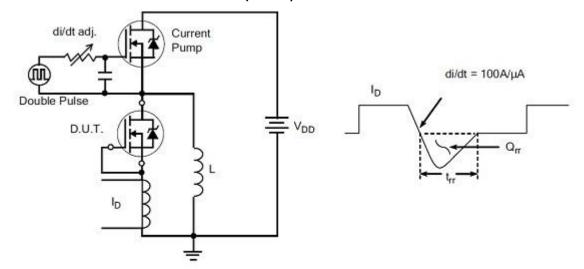


Resistive Switching Test Circuit

Resistive Switching Waveforms

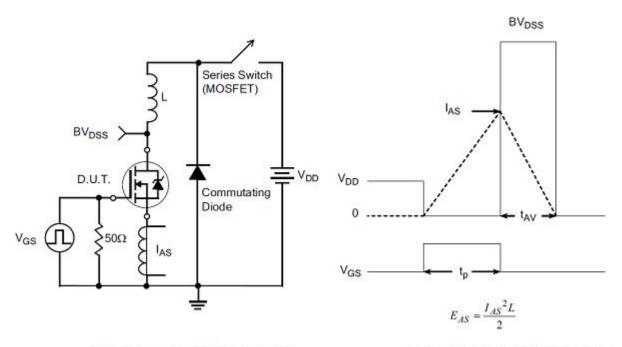


# **TEST CIRCUITS AND WAVEFORMS(Cont.)**



Diode Reverse Recovery Test Circuit

Diode Reverse Recovery Waveform



Unclamped Inductive Switching Test Circuit

Unclamped Inductive Switching Waveforms

# **Revision history**

# **Document revision history**

Date	Revision	Changes
25-Nov-2021	1.0	First release

Version: 1.0

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